To our customers,

# Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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# 2SK2958(L), 2SK2958(S)

## Silicon N Channel MOS FET
## High Speed Power Switching

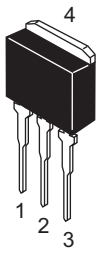
REJ03G1058-0400
(Previous: ADE-208-568B)
Rev.4.00
Sep 07, 2005

### Features

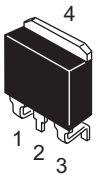
- Low on-resistance
  $R_{DS(on)}$ = 5.5 mΩ typ.
- 4 V gate drive devices.
- High speed switching

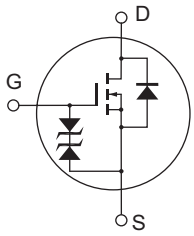
### Outline

RENESAS Package code: PRSS0004AE-A
(Package name: LDPAK(L))




RENESAS Package code: PRSS0004AE-B
(Package name: LDPAK(S)-(1))




1. Gate
2. Drain
3. Source
4. Drain

## Absolute Maximum Ratings

(Ta = 25°C)

| Item | Symbol | Ratings | Unit |
|---|---|---|---|
| Drain to source voltage | $V_{DSS}$ | 30 | V |
| Gate to source voltage | $V_{GSS}$ | ±20 | V |
| Drain current | $I_D$ | 75 | A |
| Drain peak current | $I_{D(pulse)}$ Note1 | 300 | A |
| Body-drain diode reverse drain current | $I_{DR}$ | 75 | A |
| Channel dissipation | Pch Note2 | 100 | W |
| Channel temperature | Tch | 150 | °C |
| Storage temperature | Tstg | –55 to +150 | °C |

Notes: 1. PW ≤ 10 µs, duty cycle ≤ 1 %
2. Value at Tc = 25°C

## Electrical Characteristics

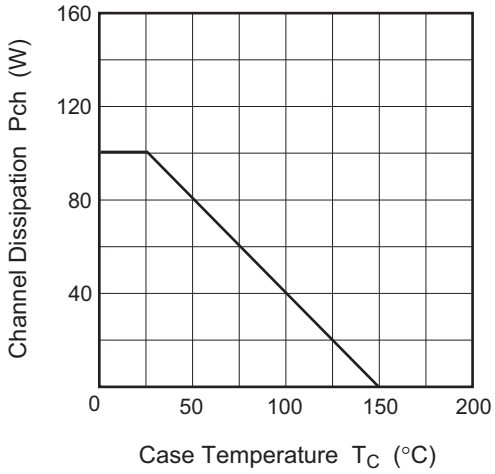
(Ta = 25°C)

| Item | Symbol | Min | Typ | Max | Unit | Test Conditions |
|---|---|---|---|---|---|---|
| Drain to source breakdown voltage | $V_{(BR)DSS}$ | 30 | — | — | V | $I_D$ = 10 mA, $V_{GS}$ = 0 |
| Gate to source breakdown voltage | $V_{(BR)GSS}$ | ±20 | — | — | V | $I_G$ = ±100 µA, $V_{DS}$ = 0 |
| Zero gate voltage drain current | $I_{DSS}$ | — | — | 10 | µA | $V_{DS}$ = 30 V, $V_{GS}$ = 0 |
| Gate to source leak current | $I_{GSS}$ | — | — | ±10 | µA | $V_{GS}$ = ±1 6V, $V_{DS}$ = 0 |
| Gate to source cutoff voltage | $V_{GS(off)}$ | 1.0 | — | 2.0 | V | $I_D$ = 1 mA, $V_{DS}$ = 10V |
| Static drain to source on state resistance | $R_{DS(on)}$ | — | 5.5 | 7.0 | mΩ | $I_D$ = 40 A, $V_{GS}$ = 10V Note3 |
| | $R_{DS(on)}$ | — | 9.0 | 14.0 | mΩ | $I_D$ = 40 A, $V_{GS}$ = 4V Note3 |
| Forward transfer admittance | $\|y_{fs}\|$ | 35 | 60 | — | S | $I_D$ = 40 A, $V_{DS}$ = 10V Note3 |
| Input capacitance | Ciss | — | 4100 | — | pF | $V_{DS}$ = 10 V, $V_{GS}$ = 0, f = 1 MHz |
| Output capacitance | Coss | — | 2700 | — | pF | |
| Reverse transfer capacitance | Crss | — | 800 | — | pF | |
| Turn-on delay time | $t_{d(on)}$ | — | 45 | — | ns | $V_{GS}$ = 10 V, $I_D$ = 40 A, $R_L$ = 0.25 Ω |
| Rise time | $t_r$ | — | 430 | — | ns | |
| Turn-off delay time | $t_{d(off)}$ | — | 460 | — | ns | |
| Fall time | $t_f$ | — | 440 | — | ns | |
| Body–drain diode forward voltage | $V_{DF}$ | — | 1.0 | — | V | $I_F$ = 75A, $V_{GS}$ = 0 |
| Body–drain diode reverse recovery time | $t_{rr}$ | — | 90 | — | ns | $I_F$ = 75A, $V_{GS}$ = 0 $di_F/dt$ = 50 A/µs |

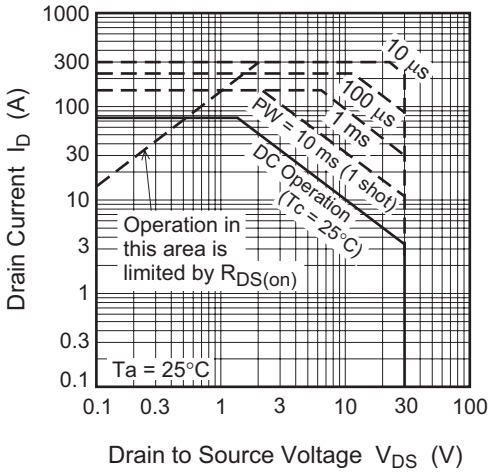
Note: 3. Pulse test

## Main Characteristics

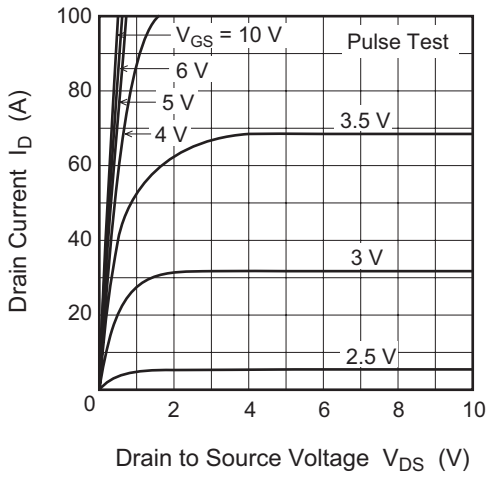
Power vs. Temperature Derating



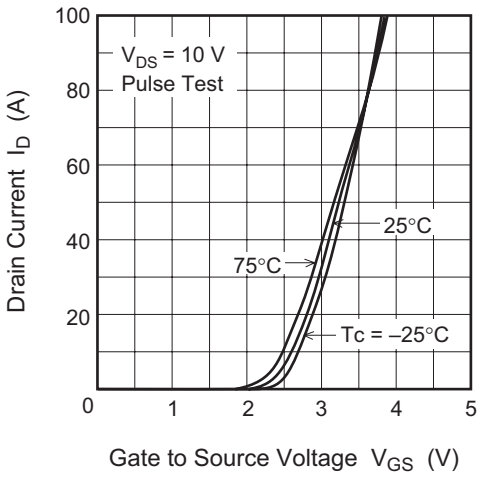

Maximum Safe Operation Area



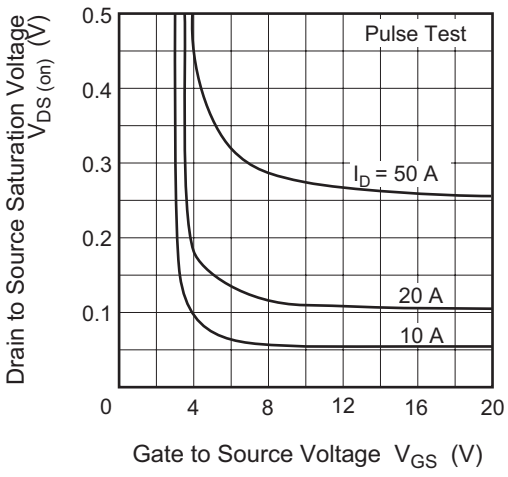

Typical Output Characteristics



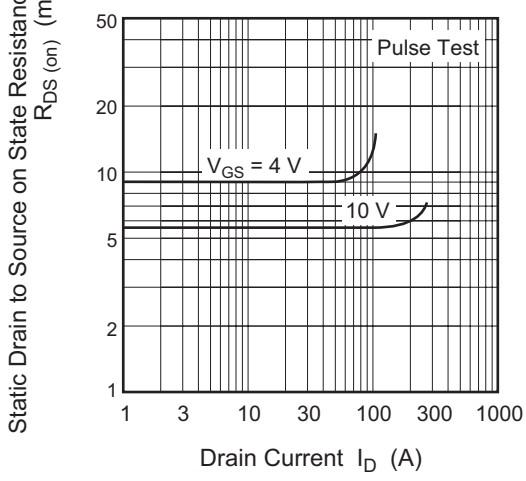

Typical Transfer Characteristics



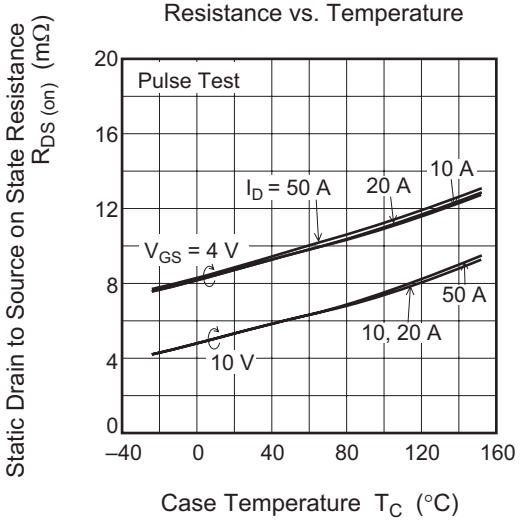

Drain to Source Saturation Voltage
vs. Gate to Source Voltage



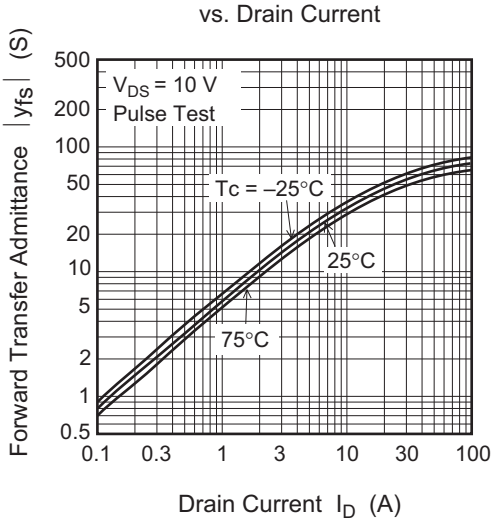

Static Drain to Source on State
Resistance vs. Drain Current



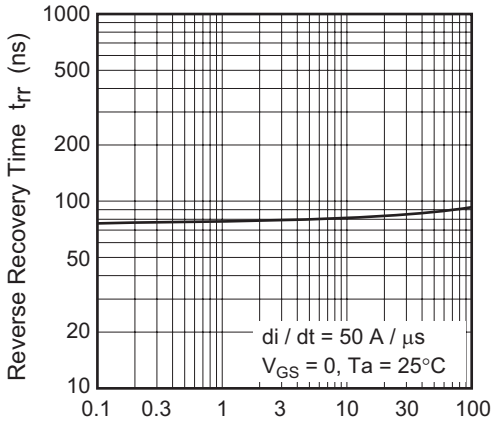
Static Drain to Source on State Resistance vs. Temperature



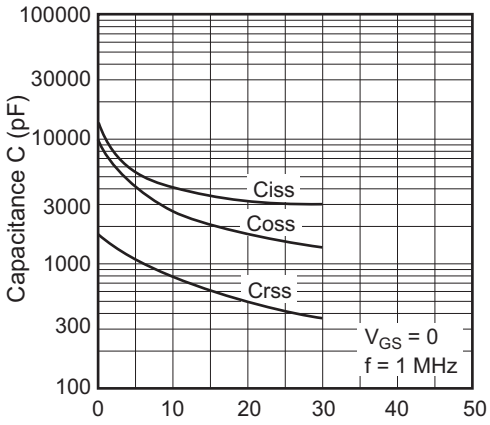

Forward Transfer Admittance vs. Drain Current



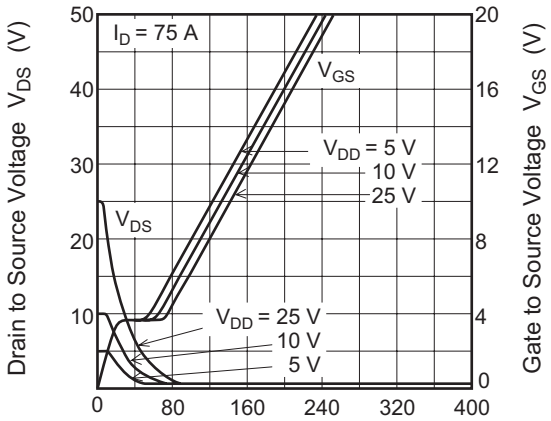

Body to Drain Diode Reverse Recovery Time



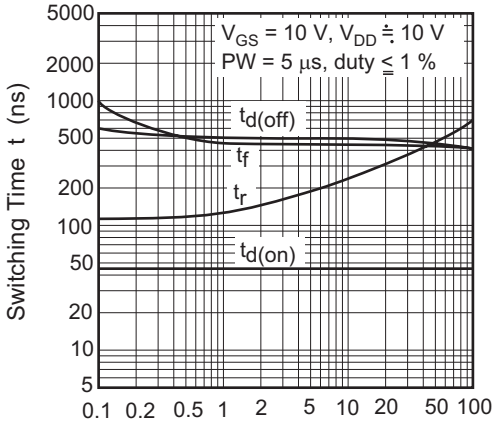

Typical Capacitance vs. Drain to Source Voltage



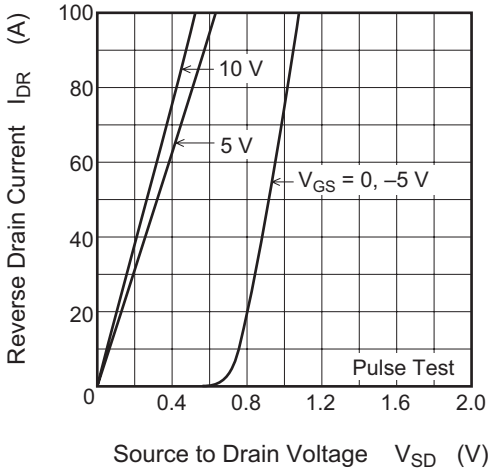

Dynamic Input Characteristics



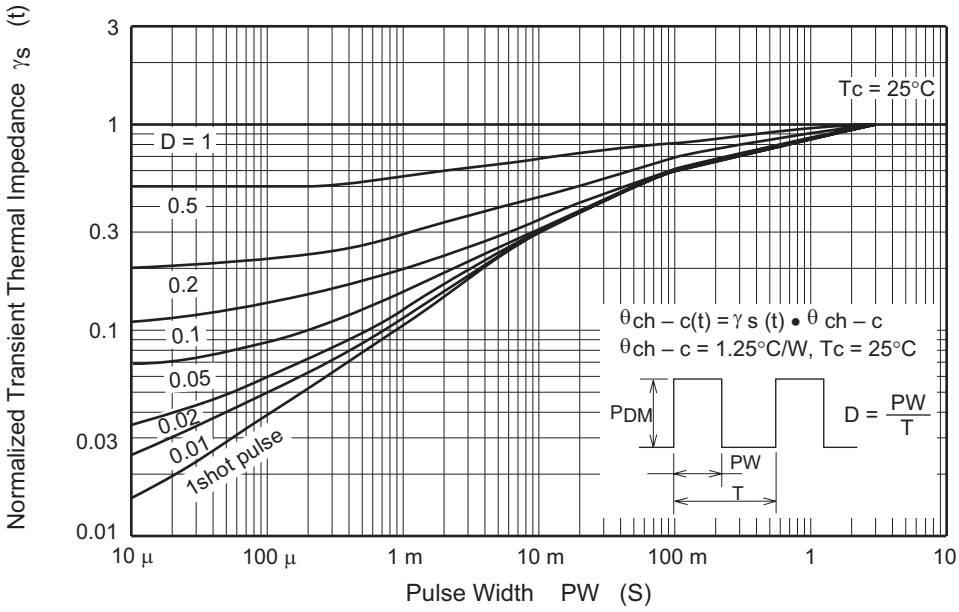

Switching Characteristics



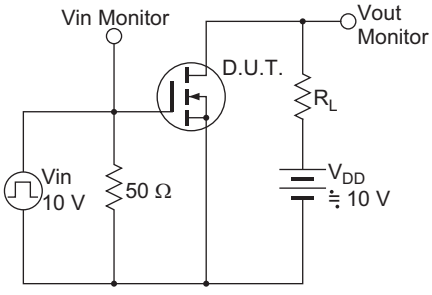
Reverse Drain Current vs.
Source to Drain Voltage



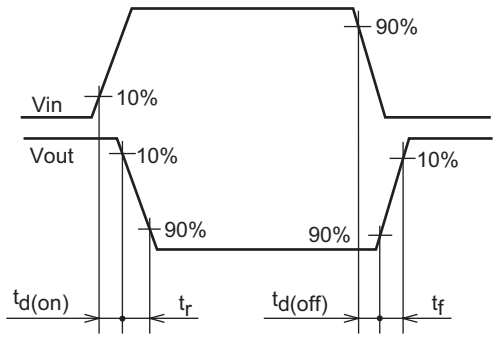

Normalized Transient Thermal Impedance vs. Pulse Width




Switching Time Test Circuit



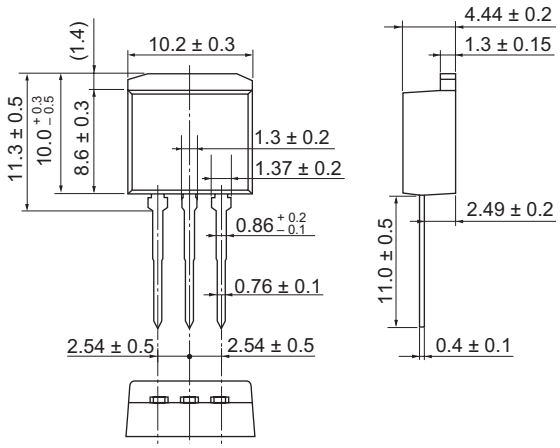

Waveform



## Package Dimensions

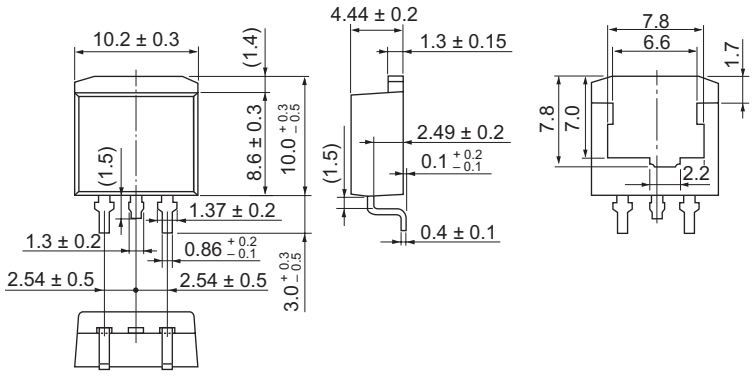
| JEITA Package Code | RENESAS Code | Package Name | MASS[Typ.] |
|---|---|---|---|
| — | PRSS0004AE-A | LDPAK(L) / LDPAK(L)V | 1.40g |

Unit: mm




| JEITA Package Code | RENESAS Code | Package Name | MASS[Typ.] |
|---|---|---|---|
| SC-83 | PRSS0004AE-B | LDPAK(S)-(1) / LDPAK(S)-(1)V | 1.30g |

Unit: mm



## Ordering Information

| Part Name | Quantity | Shipping Container |
|---|---|---|
| 2SK2958L-E | 500 pcs | Box (Sack) |
| 2SK2958STL-E | 1000 pcs | Taping |

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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